

No.1042F

LB1211 Series

General-Purpose Transistor Array

The LB1211 series are general-purpose transistor arrays containing 7 channels (5 channels: LB1217 only). They are especially suited for driving LEDs, lamps, small-sized relays, etc. The transistors can be standardized.

Features

· Common-emitter 7 channels.	LB1211,1212,1213,1214
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· Common-collector 7 channels. LB1215,1216

· Independent 5 channels LB1217

Built-in base current limiting resistors. LB1212,1213,1214,1216

· Built-in Zener diodes for level shift. LB1212

· Capable of being direct driven with TTL, CMOS, PMOS, etc.

· Wide operating voltage and temperature ranges

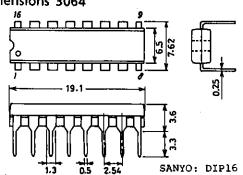
Absolute Maximum Ratings at	To - 25°C			unit	
Output Supply Voltage		LB1212/13/14 only	-0.5 to +50	V	
Collector to Emitter Voltage	~ ~	LB1211/15/16/17 only	35	v	
Collector to Base Voltage		LB1211/15/16/17 only	50	v	
Output Current	I_{OUT}	BB1211/10/10/17 Omy	200	mA	
Input Voltage		LB1212/13/14 only	-0.5 to +30	V	
input voitage	111	LB1216 only	-0.5 to +30 -0.5 to +45	V	
Input Current		LB1211/15/17 only	-0.5 to +45 25	mA	
GND Pin Current		DD1211/10/17 Only			
	I_{GND}		500	mA	
Allowable Power Dissipation	Pd max		960	mW	
Operating Temperature	Topr		-20 to +75	$^{\circ}\mathrm{C}$	
Storage Temperature	\mathbf{Tstg}		-40 to +150	$^{\circ}\mathrm{C}$	•
Electrical Characteristics at Ta	a=25°C		min typ	max	unit
Output Voltage	V _{OUT} 1	$I_{IN} = 1 \text{mA}, I_{OUT} = 10 \text{mA}$	°V Is	0.2	V
. 0	V_{OUT}^2	$I_{\rm IN} = 2 \rm mA, I_{\rm OUT} = 100 \rm mA$		0.8	v
	001	LB1212/13/14 only			Ť
	Voltr3	$I_{IN} = 3mA.I_{OUT} = 100mA$		0.8	V
	V _{OUT} 3	$I_{IN} = 3 \text{mA}, I_{OUT} = 100 \text{mA}$ LB1211/15/16/17 only		0.8	V
Output Leakage Current		$I_{IN} = 3 \text{mA}, I_{OUT} = 100 \text{mA}$ LB1211/15/16/17 only $V_{IN} = 0V, V_{OUT} = 25V$		0.8 10	
Output Leakage Current Output Sustain Voltage	I _{OFF}	LB1211/15/16/17 only V _{IN} =0V,V _{OUT} =25V	35		V μΑ V
	I _{OFF} V _{OUT} (sus)	LB1211/15/16/17 only $V_{IN} = 0V, V_{OUT} = 25V$ $I_{OUT} = 100mA$	35 50		μA
Output Sustain Voltage	I _{OFF}	LB1211/15/16/17 only V _{IN} =0V,V _{OUT} =25V		10	μA
Output Sustain Voltage	I _{OFF} V _{OUT} (sus)	LB1211/15/16/17 only V _{IN} =0V,V _{OUT} =25V I _{OUT} =100mA V _{OUT} =10V,I _{OUT} =10mA		10	μA

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Package Dimensions 3064

(unit : mm)

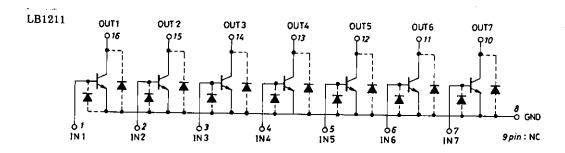
LB1211/15/16/17 only

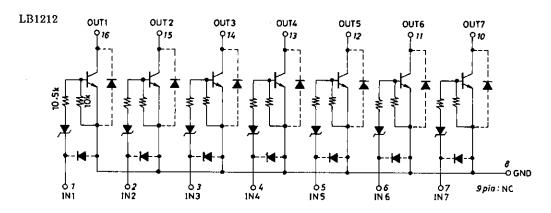


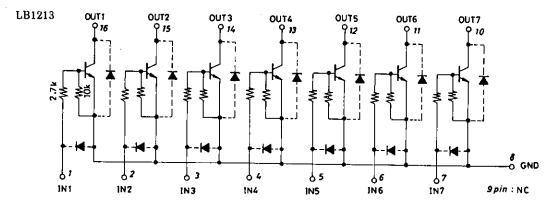
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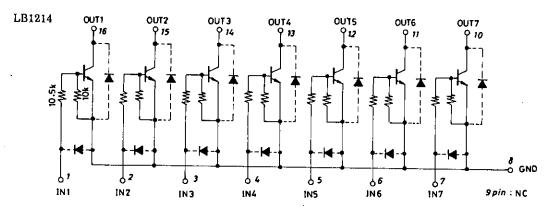
Input Voltage	$V_{IN(on)}$ $I_{IN}=1$ mA, $I_{OUT}=1$ 0mA LB1211/15/16/17 only	min 0.4	typ max	unit V	
Turn-ON Time Turn-OFF Time	t _{ON} t _{OFF}	Refer to Test Circuit. Refer to Test Circuit.	2	50 200	ns ns

Equivalent Circuit

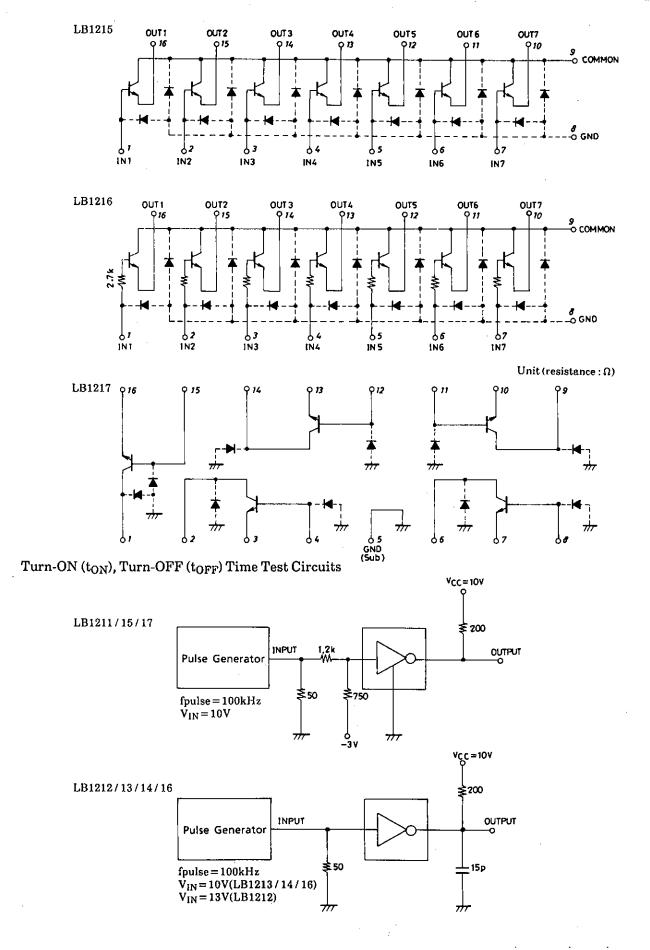






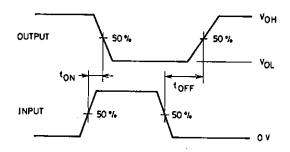


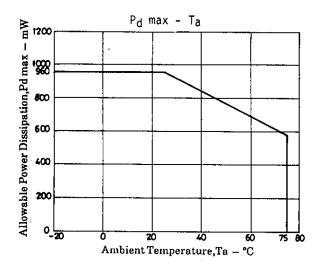
Unit (resistance : Ω)



Unit (resistance: Ω , capacitance: F)

Input/Output Waveforms





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NO.1188D

LB1231 Series

High-Voltage, Large Current Darlington Transistor Array

The circuit configuration of this IC is of 7-channel Darlington transistor array consisting of NPN transistors. It is especially suited for use in hammer drivers and lamp, relay drivers. It contains spark killer diodes against L load.

Features High-voltage (VCEO≥50V),large-current (ICmax=500mA) drive

LB1231 . Drivable by TTL, MOS output

LB1232 . Contains base current limiting resistors, Zener diodes for level shift.

. Direct drivable by 24V P MOS.

LB1233 . Contains base current limiting resistors.

. Direct drivable by TTL, C MOS output.

LB1234 . Contains base current limiting resistors.

. Direct drivable by C MOS, P MOS output.

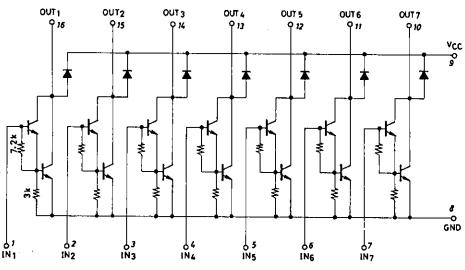
°C			unit
$v_{ ext{OUT}}$		50	V
	Per unit	500	mΑ
V _{IN}	LB1232/33/34	30	V
IIN	LB1231 only	25	mΑ
IGND	7ch simultaneously	on, 2.8	A
;	f=10Hz,duty,=23%		
$P_{\mathbf{d}}$ max	• •	1.5	W
Topr		-20 to +75	°C
$^{\mathrm{T}}$ stg		-40 to +150	°C
Ta=25°C			unit
		50	v
LB1232	$I_{OUT}=350mA$	11 to 30	V
LB1233	IOUT=350mA	3 to 30	V
LB1234	IOUT=350mA	5 to 30	v
LB1231/3	,	-0.3 to $+0.3$	V
LB1232	IOUT≦100μA	-0.3 to $+6.0$	V
LB1234	IOUT≦100µA	-0.3 to $+0.7$	v
	VIN IIN IGND Pdmax Topr Tstg Ta=25°C LB1232 LB1233 LB1234 LB1231/3 LB1232	VOUT IOUT Per unit VIN LB1232/33/34 IIN LB1231 only IGND 7ch simultaneously f=10Hz,duty,=23% Pdmax Topr Tstg Ta=25°C LB1232 IOUT=350mA LB1233 IOUT=350mA LB1234 IOUT=350mA LB1234 IOUT=350mA LB1231/33 IOUT≤100µA LB1232 IOUT≤100µA	Vout 500 Iout Per unit 500 Vin LB1232/33/34 30 Iin LB1231 only 25 IGND 7ch simultaneously on, 2.8 f=10Hz,duty,=23% Pdmax 1.5 Topr -20 to +75 Tstg -40 to +150 Ta=25°C LB1232 Iout=350mA 11 to 30 LB1234 Iout=350mA 3 to 30 LB1234 Iout=350mA 5 to 30 LB1231/33 Iout≤100μA -0.3 to +0.3 LB1232 Iout≤100μA -0.3 to +6.0

Package Dimensions 3064-D16TR (unit: mm)

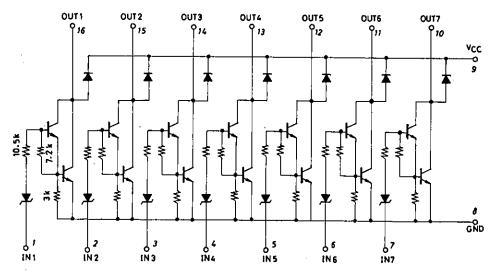
Electrical Characteristics	at Ta=25	°C	min	typ	max	unit
Output Leak Current	IOFF	V _{OUT} =50V		-21	100	ت عدد Au
Output Voltage	v_{OH1}	$I_{IN}=0.25$ mA, $I_{OUT}=100$ mA		0.9	1.1	v
	v_{OH2}	$I_{IN}=0.35$ mA, $I_{OUT}=200$ mA		1.1	1.3	V
	v_{OH3}	$I_{IN}=0.5$ mA, $I_{OUT}=350$ mA		1.3	1.6	V
	V _{OH4}	IIN=lmA,I _{OUT} =400mA			2.4	V
Input Voltage	$v_{\mathtt{IN}}$	LB1231 IIN=1mA	,	1.35	1.7	v
Input Current	v_{IN}	LB1232 V _{IN} =17V	(2.82	1.25	mA
		LB1233 V _{IN} =3.85V	(0.93	1.35	mA
		LB1234 V _{IN} =5V	4	0.35	0.5	mΑ
		LB1234 VIN=12V		1.00	1.45	mΑ
Spark Killer Diode Leak Currnet	IR(S)	$V_{R(S)}=50V$			100	Aυζ
Spark Killer Diode 🗀 🤫	V _F (S)1	$I_{F(S)} = 350 \text{mA}$			2.0	V
Forward Voltage	VF(S)2	$I_F(s) = 400 \text{mA}$			2.4	v

Equivalent Circuits LB1231

Unit (resistance: Ω)



LB1232

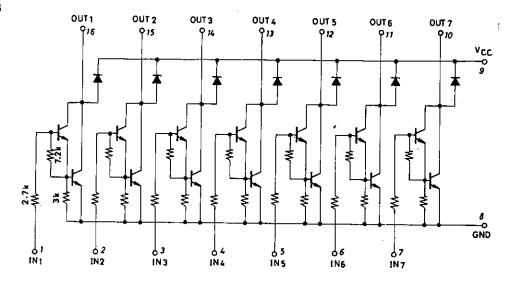


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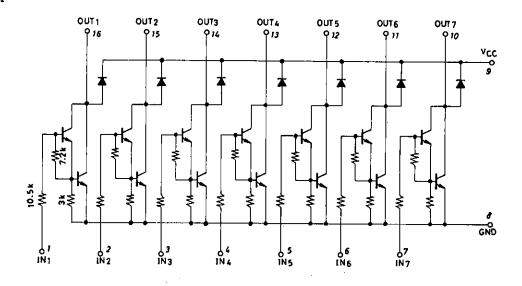
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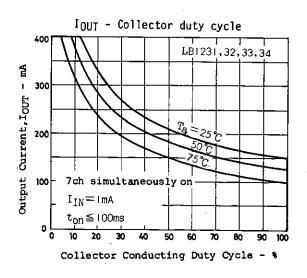
Unit (resistance: Ω)

LB1233



LB1234





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